CNZ3731, CNC7C501, CNZ3734, CNC2S501, CNC7C502, CNC7H501 (ON3731, ON3732, ON3734, ON3731A, ON3732A, ON3734A)

Optoisolators

Overview

The CNZ3731 series of optoisolators consist of a GaAs infrared LED which is optically coupled with a Si NPN Darlington phototransistor, and housed in a small DIL package. The series provides high I/O isolation voltage and high collector/emitter isolation voltage, as well as a high current transfer ratio (CTR). This opto isolator series also includes the two-channel CNC7C501 and the four-channel CNZ3734, and A type of these models with increased collector to emitter breakdown voltage (V_{CEO} > 350V).

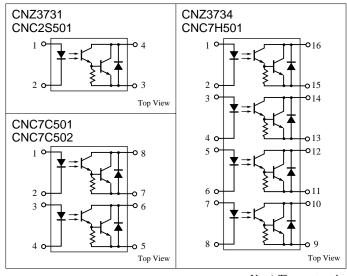
Features

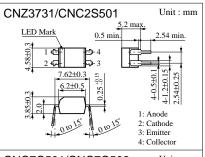
- High collector to emitter breakdown voltage : $V_{CEO} > 300 \text{ V}$, A type : $V_{CEO} > 350 \text{ V}$
- High current transfer ratio with Darlington phototransistor output : CTR = 4000% (typ.)
- High I/O isolation voltage : $V_{ISO} \ge 5000 V_{rms}$
- Small DIL package for saving mounting space
- UL listed (UL File No. E79920)
- A-type models have a guaranteed internal insulating distance of 0.4 mm

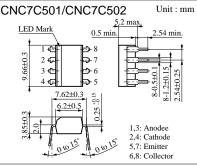
Applications

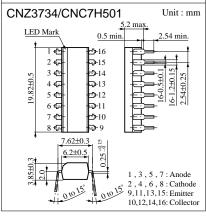
- Telephones
- Telephone exchange
- FAX
- Programmable controllers
- Signal transfer between circuits with different potentials and impedances

Pin Connection









Note) The part numbers in the parenthesis show conventional part number.

■ Absolute Maximum Ratings (Ta = 25°C)

Parameter		Symbol	Ratings				1.1-54
			CNZ3731	CNC7C501 CNZ3734	CNC2S501	CNC7C502 CNC7H501	Unit
Input (Light emitting diode)	Reverse voltage (DC)	V_R	6		6		V
	Forward current (DC)	I_{F}	50		50		mA
	Pulse forward current	I_{FP}^{*1}	1		1		A
	Power dissipation	P _D *2	75		75		mW
Output (Photo transistor)	Collector current	I_{C}	150		150		mA
	Collector to emitter voltage	V _{CEO}	300		350		V
	Emitter to collector voltage	V _{ECO}	0.3		0.3		V
	Collector power dissipation	P _C *3	300	150	300	150	mW
Total power dissipation		P _T	320	200	320	200	mW
Isolation voltage, input to output		V _{ISO} *4	5000		5000		V _{rms}
Operating ambient temperature		T _{opr}	-30 to +100		-30 to +100		°C
Storage temperature		T _{stg}	-55 to +125		-55 to +125		°C

^{*1} Pulse width ≤ 100 µs, repeat 100 pps

■ Electrical Characteristics (Ta = 25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Input characteristics	Reverse current (DC)	I_R	$V_R = 3V$			10	μΑ
	Forward voltage (DC)	V_{F}	$I_F = 50 \text{mA}$		1.35	1.5	V
	Capacitance between pins	C_t	$V_R = 0V$, $f = 1MHz$		30		pF
Output characteristics	Collector cutoff current	I _{CEO}	$V_{CE} = 200V$			200	nA
	Collector to emitter capacitance	C_{C}	$V_{CE} = 10V$, $f = 1MHz$		10		pF
Transfer characteristics	DC current transfer ratio	CTR*1	$V_{CE} = 2V$, $I_F = 1mA$	1000	4000		%
	Isolation capacitance, input to output	C _{ISO}	f = 1MHz		0.7		pF
	Isolation resistance, input to output	R _{ISO}	$V_{\rm ISO} = 500 V$	1011			Ω
	Rise time	t _r *2	$V_{CC} = 10V, I_C = 10mA,$		40		μs
	Fall time	t _f *3	$R_t = 100\Omega$		15		μs
	Collector to emitter saturation voltage	V _{CE(sat)}	$I_F = 1 \text{mA}, I_C = 2 \text{mA}$			1.0	V

^{*1} DC current transfer ratio (CTR) is a ratio of output current against DC input current.

$$CTR = \frac{I_C}{I_F} \times 100 \, (\%)$$

2

^{*2} Input power derating ratio is 0.75 mW/°C at Ta ≥ 25°C.

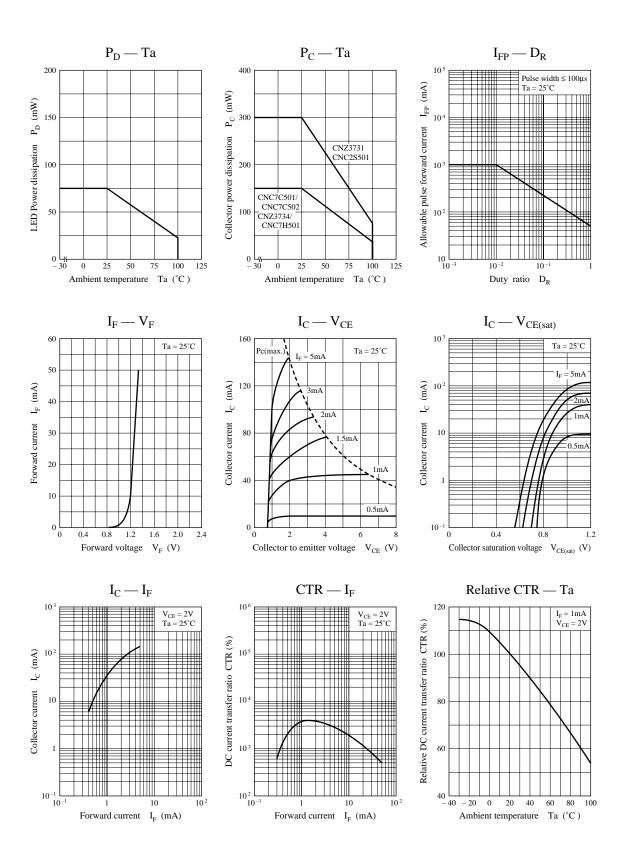
^{*3} Output power derating ratio is 3.0 mW/°C at Ta ≥ 25°C (CNZ3731, CNC2S501).

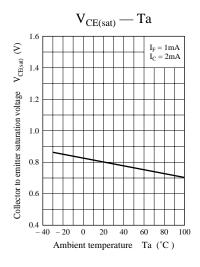
Output power derating ratio is 0.75 mW/°C at Ta ≥ 25°C (CNC7C501, CNC2S502, CNZ3734, CNC7H501).

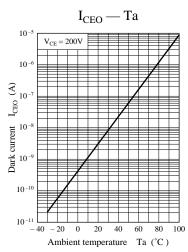
^{*4} AC 1min., RH < 60 %

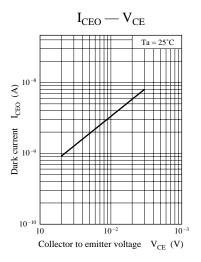
 $^{^{*2}}$ t_{r} : Time required for the collector current to increase from 10% to 90% of its final value

 $^{^{*3}}$ t_f: Time required for the collector current to decrease from 90% to 10% of its initial value





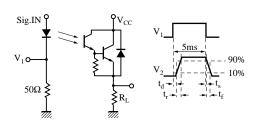




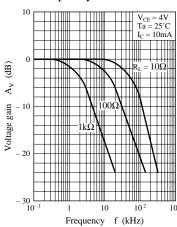
Response time — External load resistance characteristics

 $\underbrace{\left\{ \begin{array}{c} 10^{3} \\ V_{CC} = 10V \\ I_{C} = 10mA \\ Ta = 25^{\circ}C \end{array} \right.}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C} \\ I_{C} \end{array} \right]}_{10^{-1}} \underbrace{\left\{ \begin{array}{c} I_{C$

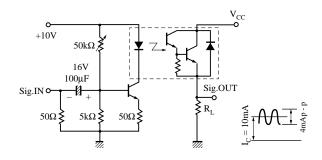
Response time measurement circuit



Frequency characteristics



Measurement circuit of frequency characteristics



Caution for Safety



Gallium arsenide material (GaAs) is used in this product.

Therefore, do not burn, destroy, cut, crush, or chemically decompose the product, since gallium arsenide material in powder or vapor form is harmful to human health

Observe the relevant laws and regulations when disposing of the products. Do not mix them with ordinary industrial waste or household refuse when disposing of GaAs-containing products.

Request for your special attention and precautions in using the technical information and semiconductors described in this material

- (1) An export permit needs to be obtained from the competent authorities of the Japanese Government if any of the products or technologies described in this material and controlled under the "Foreign Exchange and Foreign Trade Law" is to be exported or taken out of Japan.
- (2) The technical information described in this material is limited to showing representative characteristics and applied circuit examples of the products. It does not constitute the warranting of industrial property, the granting of relative rights, or the granting of any license.
- (3) The products described in this material are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).
 - Consult our sales staff in advance for information on the following applications:
 - Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
 - Any applications other than the standard applications intended.
- (4) The products and product specifications described in this material are subject to change without notice for reasons of modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the guaranteed values, in particular those of maximum rating, the range of operating power supply voltage and heat radiation characteristics. Otherwise, we will not be liable for any defect which may arise later in your equipment.
 - Even when the products are used within the guaranteed values, redundant design is recommended, so that such equipment may not violate relevant laws or regulations because of the function of our products.
- (6) When using products for which dry packing is required, observe the conditions (including shelf life and afterunpacking standby time) agreed upon when specification sheets are individually exchanged.
- (7) No part of this material may be reprinted or reproduced by any means without written permission from our company.

Please read the following notes before using the datasheets

- A. These materials are intended as a reference to assist customers with the selection of Panasonic semiconductor products best suited to their applications.
 - Due to modification or other reasons, any information contained in this material, such as available product types, technical data, and so on, is subject to change without notice.
 - Customers are advised to contact our semiconductor sales office and obtain the latest information before starting precise technical research and/or purchasing activities.
- B. Panasonic is endeavoring to continually improve the quality and reliability of these materials but there is always the possibility that further rectifications will be required in the future. Therefore, Panasonic will not assume any liability for any damages arising from any errors etc. that may appear in this material.
- C. These materials are solely intended for a customer's individual use.

 Therefore, without the prior written approval of Panasonic, any other use such as reproducing, selling, or distributing this material to a third party, via the Internet or in any other way, is prohibited.